

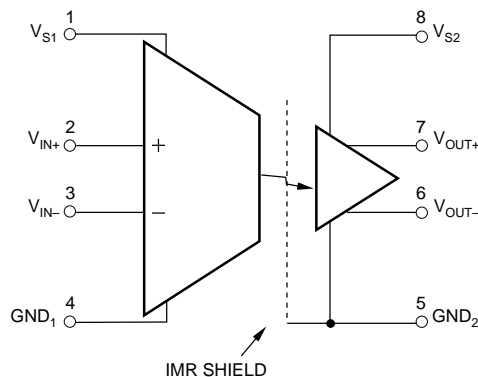


ISO130

High IMR, Low Cost ISOLATION AMPLIFIER

FEATURES

- HIGH ISOLATION-MODE REJECTION:
10kV/ μ s (min)
- LARGE SIGNAL BANDWIDTH: 85kHz (typ)
- DIFFERENTIAL INPUT/DIFFERENTIAL
OUTPUT
- VOLTAGE OFFSET DRIFT vs
TEMPERATURE: 4.6 μ V/ $^{\circ}$ C (typ)
- OFFSET VOLTAGE 1.8mV (max)
- INPUT REFERRED NOISE: 300 μ Vrms (typ)
- NONLINEARITY: 0.25% (max)
- SINGLE SUPPLY OPERATION
- SIGMA-DELTA A/D CONVERTER
TECHNOLOGY
- WORLDWIDE SAFETY APPROVAL:
UL1577 (File No. E162573), VDE0884
(File No. 85511), CSA22.2 (File No. 88324)
- AVAILABLE IN 8-PIN PLASTIC DIP and
8-PIN GULL-WING PLASTIC SURFACE
MOUNT



APPLICATIONS

- MOTOR AND SCR CONTROL
- MOTOR PHASE CURRENT SENSING
- INDUSTRIAL PROCESS CONTROL:
Transducer Isolator, Isolator for
Thermocouples, RTDs
- GENERAL PURPOSE ANALOG SIGNAL
ISOLATION
- POWER MONITORING
- GROUND LOOP ELIMINATION

DESCRIPTION

The ISO130 is a high isolation-mode rejection, isolation amplifier suited for motor control applications. Its versatile design provides the precision and stability needed to accurately monitor motor currents in high-noise motor control environments. The ISO130 can also be used for general analog signal isolation applications requiring stability and linearity under severe noise conditions.

The signal is transmitted digitally across the isolation barrier optically, using a high-speed AlGaAs LED. The remainder of the ISO130 is fabricated on 1 μ m CMOS IC process. A sigma-delta analog-to-digital converter, chopper stabilized amplifiers and differential input and output topologies make the isolation amplifier suitable for a variety of applications.

The ISO130 is easy to use. No external components are required for operation. The key specifications are 10kV/ μ s isolation-mode rejection, 85kHz large signal bandwidth, and 4.6 μ V/ $^{\circ}$ C V_{OS} drift. A single power supply ranging from +4.5V to +5.5V makes this amplifier ideal for low power isolation applications.

The ISO130 is available in 8-pin plastic DIP and 8-pin plastic gull-wing surface mount packages.

SPECIFICATIONS

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ISOLATION SPECIFICATIONS – VDE0884 INSULATION CHARACTERISTICS

At V_{IN-} , $V_{IN+} = 0V$, $T_A = 25^\circ C$, V_{S1} , $V_{S2} = 5.0V$ unless otherwise noted.

PARAMETER	CONDITIONS	ISO130P/ISO130PB ISO130U/ISO130UB	
		CHARACTERISTIC	UNITS
ISOLATION CHARACTERISTICS			
Installation Classification Table I	As Per VDE0109/12.83	I-IV	
Rated Mains Voltage $\leq 300V_{rms}$		I-III	
Rated Mains Voltage $\leq 600V_{rms}$		40/85/21	
Climatic Classification		2	
Pollution Degree ⁽¹⁾	As Per VDE0109/12.83	600	Vrms
Maximum Working Insulation Voltage (V_{IORM})		960	Vrms
Side A to Side B Test Voltage, Method b (V_{PR}) ⁽⁹⁾		720	Vrms
Partial Discharge < 5pC	$V_{PR} = 1.6 \times V_{IORM}$, $t_p = 1s$	6000	V_{PEAK}
Side A to Side B Test Voltage, Method a (V_{PR}) ⁽⁹⁾	Type and Sample Test		
Partial Discharge < 5pC	$V_{PR} = 1.2 \times V_{IORM}$, $t_p = 60s$		
Highest Allowable Overvoltage (V_{TR}) ⁽⁹⁾	Transient Overvoltage, $t_{TR} = 10s$		
Safety-Limiting Values			
Case Temperature (T_{SI})		175	$^\circ C$
Input Power ($P_{SI (INPUT)}$)		80	mW
Output Power ($P_{SI (OUTPUT)}$)		250	mW
INSULATION RELATED SPECIFICATIONS			
Min. External Air Gap (clearance)		> 7	mm
Min. External Tracking Path (creepage)		8	mm
Internal Isolation Gap (clearance)		0.5	mm
Tracking Resistance (CTI)		175	V
Isolation Group	per VDE0109	III a	
Insulation Resistance	25 $^\circ C$, $V_{ISO} = 500V$	$\geq 10^{11}$	Ω

SPECIFICATIONS

ISOLATION SPECIFICATIONS

At V_{IN+} , $V_{IN-} = 0V$, $T_A = 25^\circ C$, V_{S1} , $V_{S2} = 5.0V$, unless otherwise noted.

PARAMETER	CONDITIONS	ISO130P, ISO130PB ISO130U, ISO130UP			UNITS
		MIN	TYP	MAX	
ISOLATION					
Input-Output Surge Withstand Voltage ^(8, 9) (In accordance with UL1577)	$t = 1_{MIN}$, RH $\leq 50\%$	3750			Vrms
Barrier Impedance ⁽⁹⁾					
Resistance	$V_{ISO} = 500VDC$		10^{13}		Ω
Capacitance	$f = 1MHz$		0.7		pF
Isolation Mode Voltage Errors					
Rising Edge Transient Immunity	$V_{IM} = 1kV$, $\partial V_{OUT} < 50mV$	10	25		kV/ μs
Falling Edge Transient Immunity	$V_{IM} = 1kV$, $\partial V_{OUT} < 50mV$	10	15		kV/ μs
Isolation Mode Rejection Ratio ⁽²⁾			> 140		dB

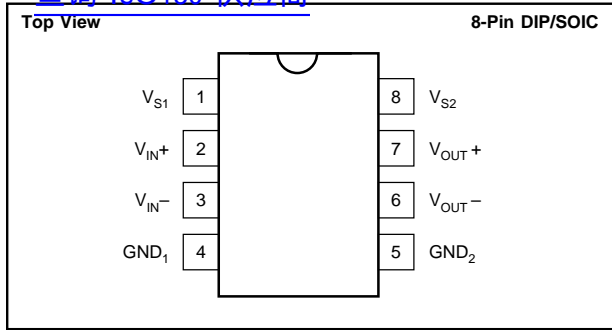
SPECIFICATIONS

At V_{IN+} , $V_{IN-} = 0V$, $T_A = 25^\circ C$, V_{S1} , $V_{S2} = 5.0V$ unless otherwise noted.

PARAMETER	CONDITIONS	ISO130P/ISO130PB ISO130U/ISO130UB			UNITS
		MIN	TYP	MAX	
INPUT					
Initial Offset Voltage		-1.8	-0.9	0.0	mV
vs Temperature			4.6		$\mu V/^\circ C$
vs V_{S1}			30		$\mu V/V$
vs V_{S2}			-40		$\mu V/V$
Power Supply Rejection; V_{S1} and V_{S2} Together	1MHz Square Wave, 5ns Rise/Fall Time		5		mV/V
Noise	0.1Hz to 100kHz		300		μV_{rms}
Input Voltage Range		-200		200	mV
Maximum Input Voltage Range before Output Clipping			± 300		mV
Initial Input Bias Current ⁽³⁾			-670		nA
vs Temperature			3		nA/ $^\circ C$
Input Resistance ⁽³⁾			530		k Ω
vs Temperature			0.38		%/ $^\circ C$
Common-Mode Rejection Ratio ⁽⁴⁾			72		dB
GAIN⁽⁵⁾					
Initial Gain					V/V
ISO130P/ISO130U	$-200mV < V_{IN+} < 200mV$	7.61	8.00	8.40	V/V
ISO130PB/ISO130UB	$-200mV < V_{IN+} < 200mV$	7.85	7.93	8.01	V/V
Gain vs Temperature			10		ppm/ $^\circ C$
Gain vs V_{S1}			2.1		ppm/mV
Gain vs V_{S2}			-0.6		ppm/mV
Gain Nonlinearity					%
for $-200mV < V_{IN+} < 200mV$			0.2	0.35	%
for $-100mV < V_{IN+} < 100mV$			0.1	0.25	%
vs Temperature ⁽⁶⁾	$-200mV < V_{IN+} < 200mV$		-0.001		% pts/ $^\circ C$
vs V_{S1} ⁽⁶⁾	$-200mV < V_{IN+} < 200mV$		-0.005		% pts/V
vs V_{S2} ⁽⁶⁾	$-200mV < V_{IN+} < 200mV$		-0.007		% pts/V
OUTPUT					
Voltage Range					V
High	$V_{IN+} = +500mV$		3.61		V
Low	$V_{IN+} = -500mV$		1.18		V
Common-Mode Voltage	$-40^\circ C < T_A < 85^\circ C$, $4.5V < V_{S1} < 5.5V$	2.2	2.39	2.6	V
Current Drive ⁽⁷⁾			1		mA
Short-Circuit Current	$V_{OUT} = 0V$ or $V_{OUT} = V_{S2}$		9.3		mA
Output Resistance			11		Ω
vs Temperature			0.6		%/ $^\circ C$
FREQUENCY RESPONSE					
Bandwidth					kHz
-3dB	$-40^\circ C$ to $85^\circ C$	50	85		kHz
-45°			35		kHz
Rise/Fall Time (10% - 90%)	$-40^\circ C$ to $85^\circ C$		4.3	6.6	μs
Propagation Delay					μs
to 10%	$-40^\circ C$ to $85^\circ C$		2.0	3.3	μs
to 50%	$-40^\circ C$ to $85^\circ C$		3.4	5.6	μs
to 90%	$-40^\circ C$ to $85^\circ C$		6.3	9.9	μs
POWER SUPPLIES					
Rated Voltage			5.0		V
Voltage Range		4.5		5.5	V
Quiescent Current					mA
V_{S1}	$V_{IN+} = 200mV$, $-40^\circ C < T_A < 85^\circ C$, $4.5V < V_{S1} < 5.5V$		10.7	15.5	mA
V_{S2}	$-40^\circ C < T_A < 85^\circ C$, $4.5V < V_{S1} < 5.5V$		11.6	15.5	mA
TEMPERATURE RANGE					
Specification		-40		85	$^\circ C$
Operating		-40		100	$^\circ C$
Storage		-55		125	$^\circ C$
θ_{C-A}			86		$^\circ C/W$

NOTES: (1) This part may also be used in Pollution Degree 3 environments where the rated mains voltage is 300Vrms (per DIN VDE0109/12.83). (2) IMRR = $20 \log (\partial V_{IN} / \partial V_{ISO})$. (3) Time averaged value. (4) $V_{IN+} = V_{IN-} = V_{CM}$. CMRR = $20 \log (\partial V_{CM} / \partial V_{OS})$. (5) The slope of the best-fit line of ($V_{OUT+} - V_{OUT-}$) vs ($V_{IN+} - V_{IN-}$). (6) Change in nonlinearity vs temperature or supply voltage expressed in number of percentage points per $^\circ C$ or volt. (7) For best offset voltage performance. (8) For devices with minimum V_{ISO} specified at 3750Vrms, each isolation amplifier is proof-tested by applying an insulation test voltage $\geq 4500V_{rms}$ for 1 second (leakage current $< 5\mu A$). This specification does not guarantee continuous operation. (9) Pins 1-4 are shorted together and pins 5-8 are shorted together for this test.

PIN CONFIGURATION
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 **ELECTROSTATIC DISCHARGE SENSITIVITY**

This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ABSOLUTE MAXIMUM RATINGS

Supply Voltages: V_{S1}, V_{S2}	0V to 5.5V
Steady-State Input Voltage	-2V to $V_{S1} + 0.5V$
2 Second Transient Input Voltage	-6.0V
Output Voltages: V_{OUT+}, V_{OUT-}	-0.5V to $V_{S2} + 0.5V$
Lead Temperature Solder (1.6mm below seating plane, 10s)	260°C

PACKAGE INFORMATION⁽¹⁾

MODEL	PACKAGE	PACKAGE DRAWING NUMBER
ISO130P	8-Pin Plastic DIP	006-3
ISO130PB	8-Pin Plastic DIP	006-3
ISO130U	8-Pin Gull-Wing Plastic Surface Mount	006-2
ISO130UB	8-Pin Gull-Wing Plastic Surface Mount	006-2

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix D of Burr-Brown IC Data Book.

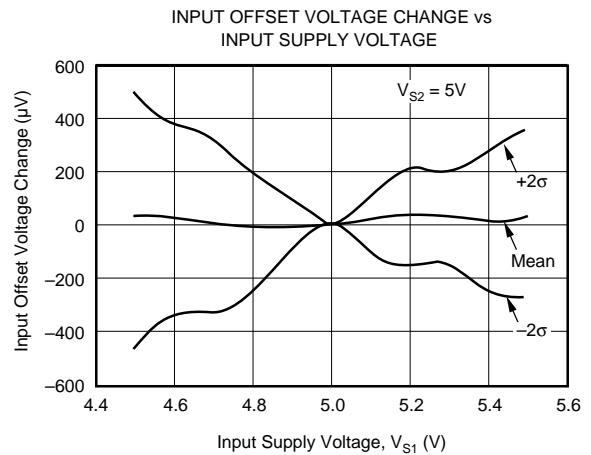
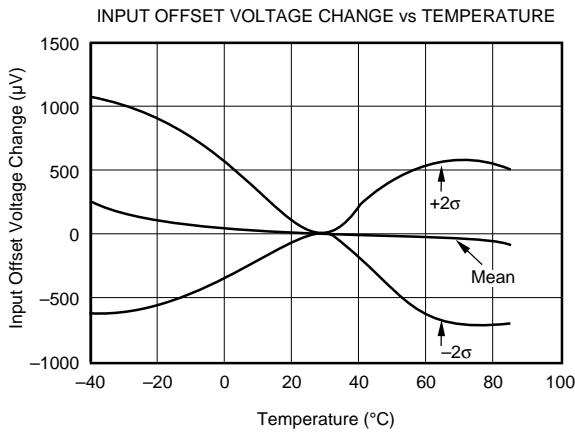
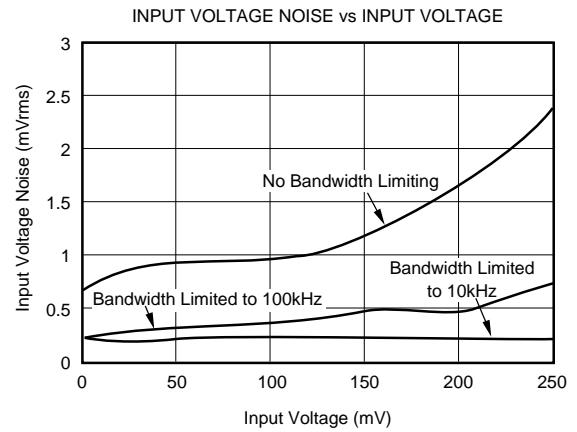
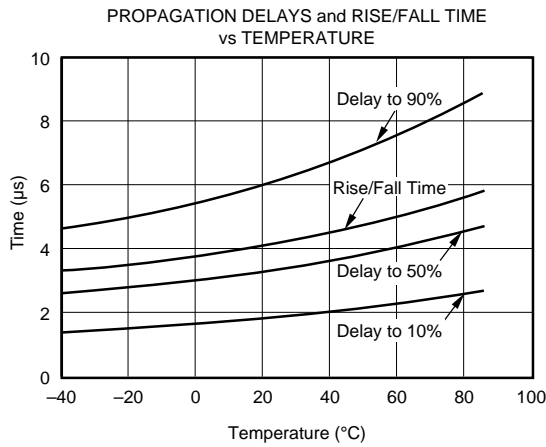
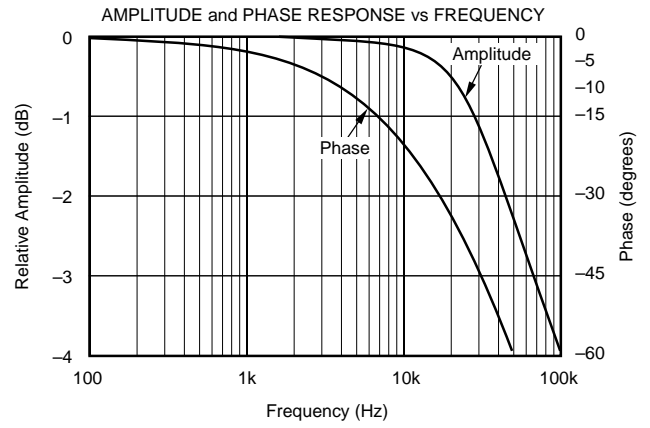
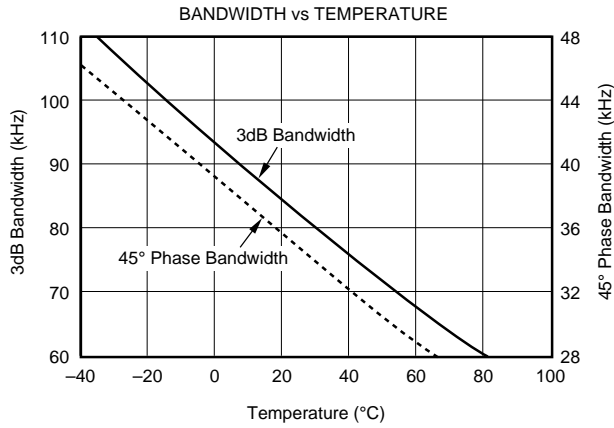
ORDERING INFORMATION

MODEL	PACKAGE	GAIN ERROR (MAX)
ISO130P	8-Pin Plastic DIP	±5% (mean value = 8.00)
ISO130PB	8-Pin Plastic DIP	±1% (mean value = 7.93)
ISO130U	8-Pin Gull-Wing Plastic Surface Mount	±5% (mean value = 8.00)
ISO130UB	8-Pin Gull-Wing Plastic Surface Mount	±1% (mean value = 7.93)

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TYPICAL PERFORMANCE CURVES

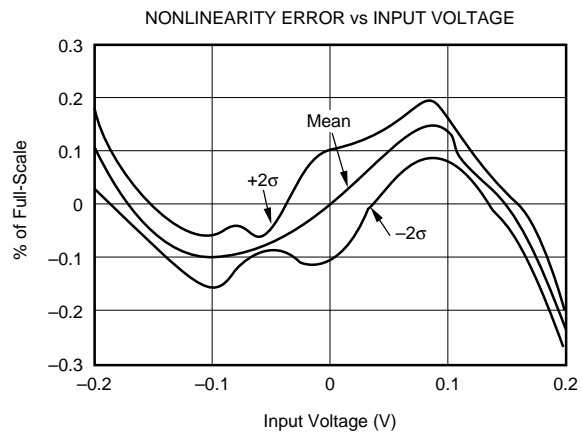
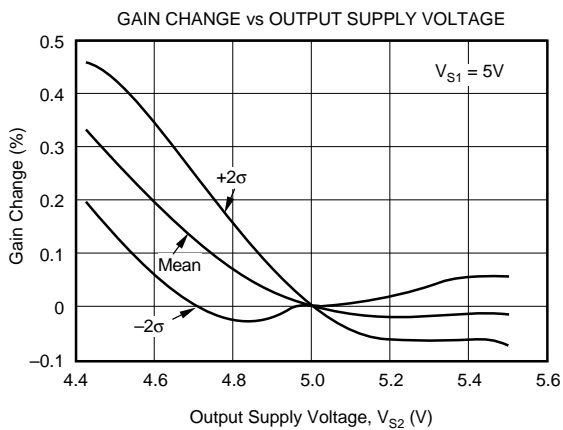
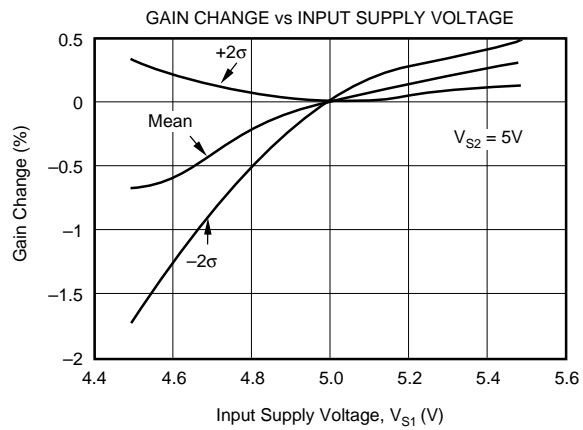
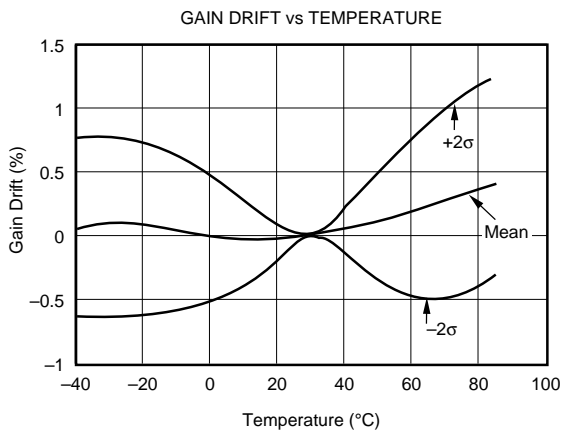
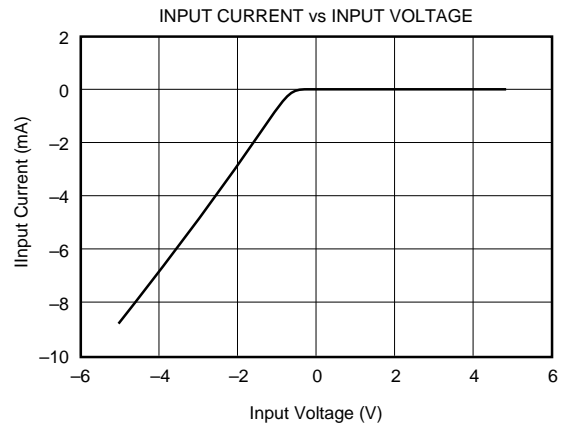
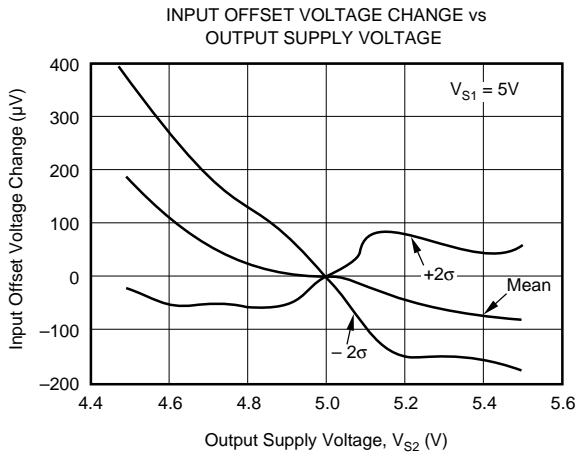
At $T_A = 25^\circ\text{C}$, $V_{S1} = V_{S2} = 5.0\text{V}_{\text{DC}}$, $V_{\text{IN}+}$, $V_{\text{IN}-} = 0\text{V}$ unless otherwise noted.



TYPICAL PERFORMANCE CURVES (CONT)

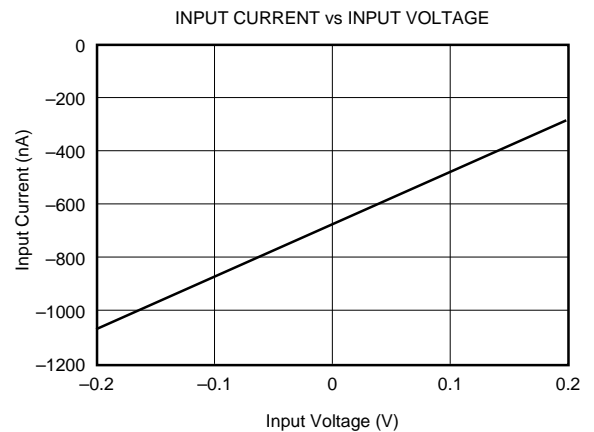
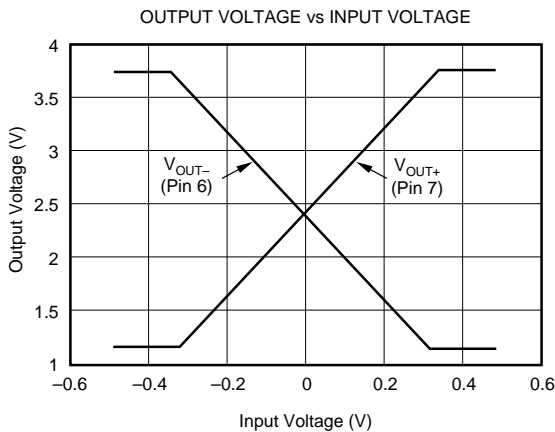
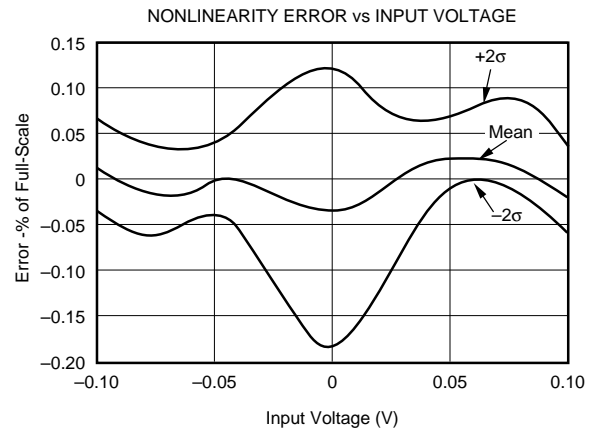
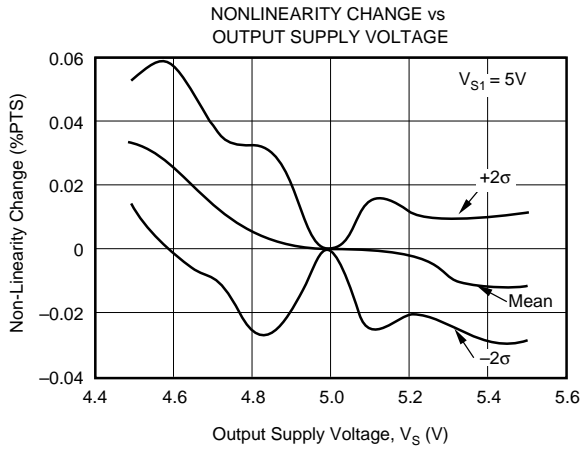
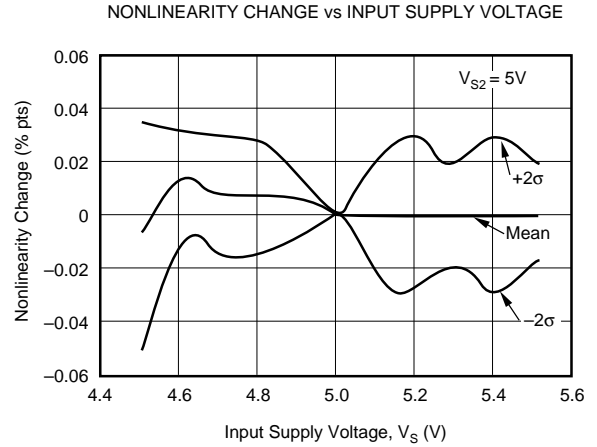
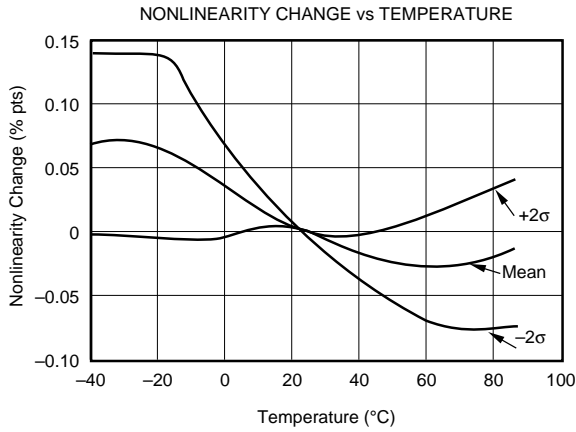
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At $T_A = 25^\circ\text{C}$, $V_{S1}, V_{S2} = 5.0\text{V}_{\text{DC}}$, $V_{\text{IN}+}, V_{\text{IN}-} = 0\text{V}$ unless otherwise noted.



查询 ISO130 供应商 TYPICAL PERFORMANCE CURVES (CONT)

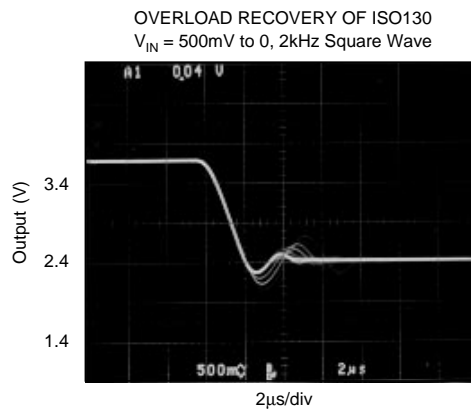
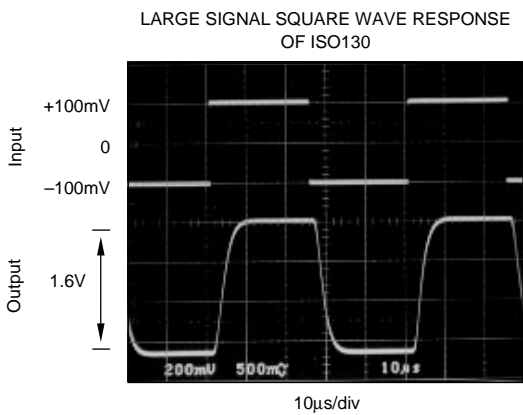
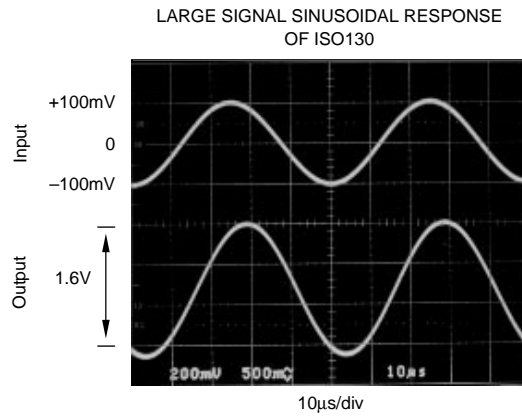
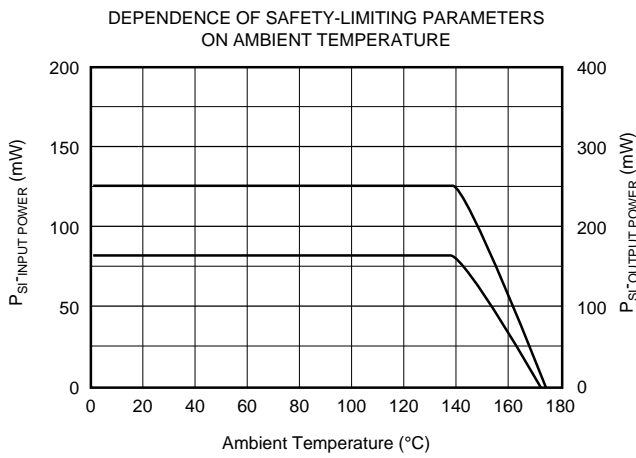
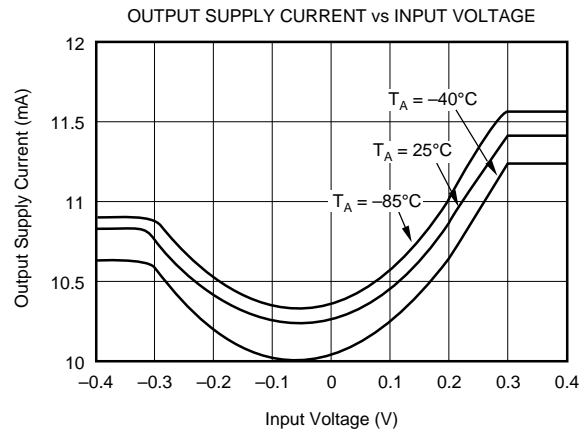
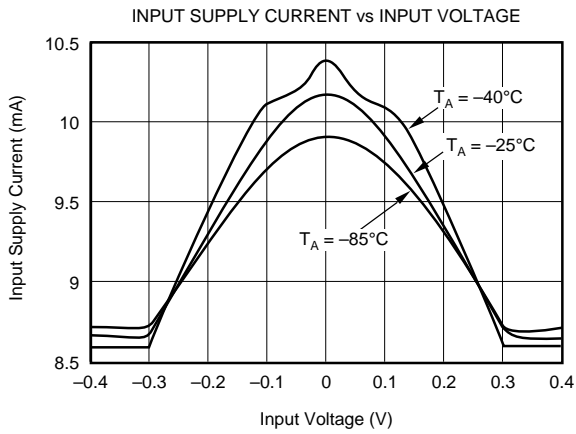
At $T_A = 25^\circ\text{C}$, $V_{S1}, V_{S2} = 5.0V_{DC}$, $V_{IN+}, V_{IN-} = 0V$ unless otherwise noted.



TYPICAL PERFORMANCE CURVES (CONT)

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At $T_A = 25^\circ\text{C}$, V_{S1} , $V_{S2} = 5.0\text{V}_{\text{DC}}$, $V_{\text{IN}+}$, $V_{\text{IN}-} = 0\text{V}$ unless otherwise noted.



THEORY OF OPERATION

The ISO130 isolation amplifier (Figure 1) uses an input and output section galvanically isolated by a high speed optical barrier built into the plastic package. The input signal is converted to a time averaged serial bit stream by use of a sigma-delta analog-to-digital converter and then optically transmitted digitally across the isolation barrier. The output section receives the digital signal and converts it to an analog voltage, which is then filtered to produce the final output signal.

Internal amplifiers are chopper-stabilized to help maintain device accuracy over time and temperature. The encoder circuit eliminates the effects of pulse-width distortion of the optically transmitted data by generating one pulse for every edge of the converter data to be transmitted. This coding scheme reduces the effects of the non-ideal characteristics of the LED, such as non-linearity and drift over time and temperature.

ISOLATION AND INSULATION SPECIFICATIONS

The performance of the isolation barrier of the ISO130 is specified with three specifications, two of which require high voltage testing. In accordance with UL1577, the barrier integrity of each isolation amplifier is proof-tested by applying an insulation test voltage greater than or equal to

4500Vrms for one second. This is to guarantee the isolation amplifier will survive a 3750V transient voltage. The barrier leakage current test limit is 5 μ A. Pins 1-4 are shorted together and pins 5-8 are shorted together during the test.

This test is followed by the partial discharge isolation voltage test as specified in the German VDE0884. This method requires the measurement of small current pulses (<5pico Colomb) while applying 960Vrms across every ISO130 isolation barrier. This guarantees 600Vrms continuous isolation (V_{ISO}) voltage. No partial discharge may be initiated to pass this test. This criterion confirms transient overvoltage (1.6 x 600Vrms) protection without damage to the ISO130.

This test method represents “state of the art” for nondestructive high voltage reliability testing. It is based on the effects of nonuniform fields that exist in heterogeneous dielectric material during barrier degradation. In the case of void non-uniformities, electric field stress begins to ionize the void region before bridging the entire high voltage barrier. The transient conduction of charge during and after the ionization can be detected externally as a burst of 0.01 to 0.1 μ s current pulses that repeat on each AC voltage cycle. The minimum AC barrier voltage that initiates partial discharge is defined as the “inception voltage”. Decreasing the barrier voltage to a lower level is required before partial discharge ceases and is defined as the “extinction voltage”.

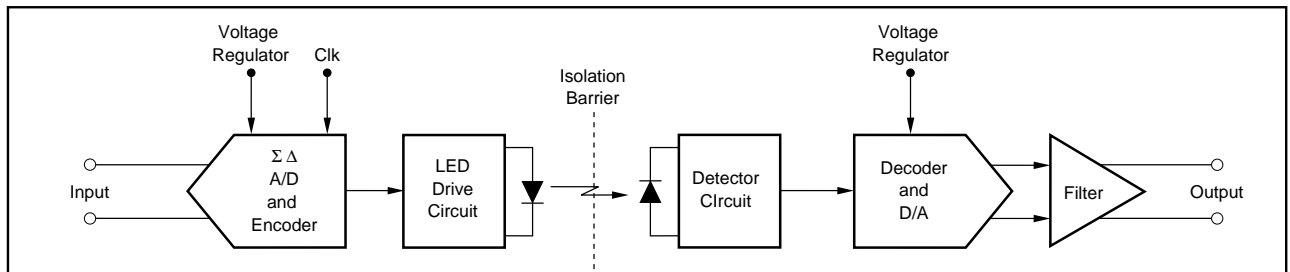


FIGURE 1. Block Diagram of ISO130 Isolation Amplifier.

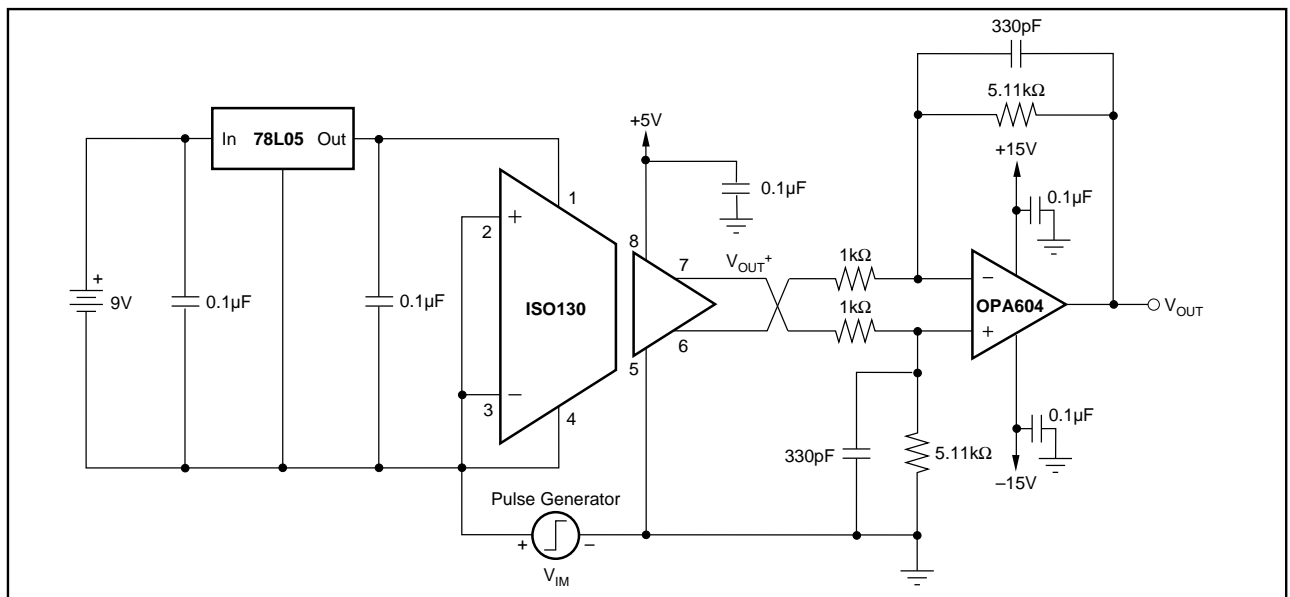


FIGURE 2. Isolation Mode Rejection and Transient Immunity Test Circuit.

Both tests are 100% production tests. The partial discharge testing of the ISO130 is performed after the UL1577 test criterion giving more confidence in the barrier reliability.

The third guaranteed isolation specification for the ISO130 is Transient Immunity (TI), which specifies the minimum rate of rise or fall of an isolation mode noise signal at which small output perturbations begin to occur. An isolation mode signal is defined as a signal appearing between the isolated grounds, GND_1 and GND_2 . Isolation Mode Voltage (IMV) is the voltage appearing between isolated grounds. Under certain circumstances this voltage across the isolation barrier can induce errors at the output of the isolation amplifier. Figure 2 shows the Transient Immunity Test Circuit for the ISO130. In this test circuit a pulse generator is placed between the isolated grounds (GND_1 and GND_2). The inputs of the ISO130 are both tied to GND_1 . A difference amplifier is used

to gain the output signal of the ISO130. A Transient Immunity failure is determined when the output of the ISO130 changes by more than 50mV as illustrated in Figure 3.

Finally, Isolation Mode Rejection Ratio (typically >140dB for the ISO130) is defined as the ratio of differential signal gain to the isolation mode gain at 60Hz. The magnitude of the 60Hz voltage across the isolation barrier during this test is not so large as to cause Transient Immunity errors. The Isolation Mode Rejection Ratio should not be confused with the Common Mode Rejection Ratio. The Common Mode Rejection Ratio defines the relationship of differential signal gain (signal applied differentially between pins 2 and 3) to the common mode gain (input pins tied together and the signal applied to both inputs at the same time).

APPLICATIONS INFORMATION

APPLICATION CIRCUITS

Figure 4 illustrates a typical application for the ISO130. In this motor control circuit, the current that is sent to the motor is sensed by the resistor, R_{SENSE} . The voltage drop across this resistor is gained up by the ISO130 and then transmitted across the isolation barrier. A difference amplifier, A_2 , is used to change the differential output signal of the ISO130 to a single ended signal. This voltage information is then sent to the control circuitry of the motor. The ISO130 is particularly well suited for this application because of its superior Transient Immunity (10kV/ μ s, max) and its excellent immunity to RF noise.

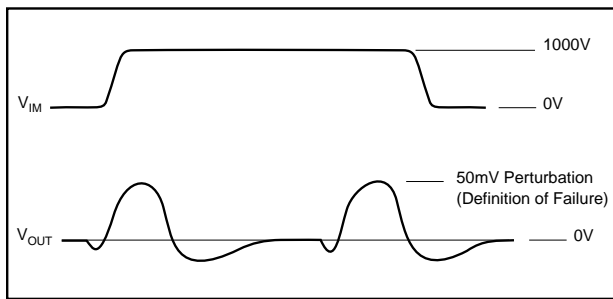


FIGURE 3. Typical Transient Immunity Failure Waveform.

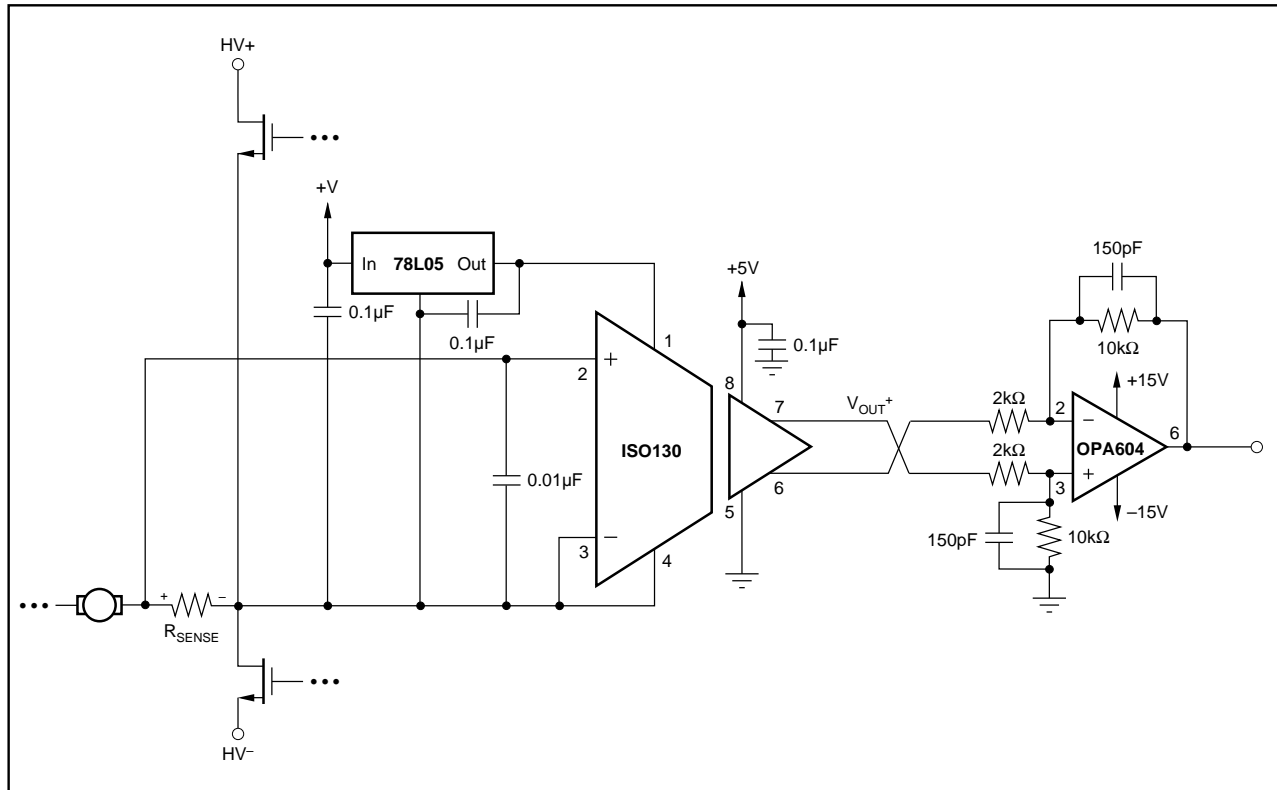


FIGURE 4. ISO130 Used to Monitor Motor Current.

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The current-sensing resistor should have a relatively low value of resistance (to minimize power dissipation), a fairly low inductance (to accurately reflect high-frequency signal components), and a reasonably tight tolerance (to maintain overall circuit accuracy).

LAYOUT SUGGESTIONS

1. Bypass capacitors should be located as close as possible to the input and output power supply pins.
2. In some applications, offset voltage can be reduced by placing a 0.01 μ F capacitor from pin 2 and/or pin 3 to GND₁. This noise can be caused by the combination of long input leads and the switched-capacitor nature of the input circuit. This capacitor(s) should be placed as close to the isolation amplifier as possible.
3. The trace lengths at input should be kept short or a twisted wire pair should be used to minimize EMI and inductance effects. For optimum performance, the input signal should be as close to the input pins as possible.
4. A maximum distance between the input and output sides of the isolation amplifier should be maintained in the layout in order to minimize stray capacitance. This practice will help obtain optimal Isolation Mode performance. Ground planes should not pass below the device on the PCB.
5. Care should be taken in selecting isolated power supplies or regulators. The ISO130 can be affected by changes in the power supply voltages. Carefully regulated power supplies are recommended.
6. For improved nonlinearity and nonlinearity temperature drift performance, pin 3 should be tied to GND₁ and the input voltage range of pin 2 should be less than 100mV.